

Technical Data Sheet

Laser Direct Writer
UVW02



SPECIFICATION

MASKLESS LITHOGRAPHY

LASER DIRECT WRITER

UVW02

Product Information

- Photolithography for various devices
 - Manufacturing unit devices for research
 - Semiconductor devices, solar devices,
 - Microfluidic channel, lab-on-a-chip
- Optical microscope + 405 nm laser focus
- Objectives: 5x, 10x, 20x, 50x, 100x
- automatic switching
- Laser focus, sample focus switchable
- Autofocus function included as standard
- hardware: XYZ motorized micro-stage and optical microscope
- image writing software: open black-and-white image files with patterns and write the pattern like a pen, tracing shortest paths
- vector line drawing: The user draws lines directly with the mouse while looking at the microscope image of the board, and the scanner draws a pattern along these lines.
- 2 writing modes: area filling with low resolution + line drawing with high resolution
- Photoresist: compatible for general optical lithography PR
- Applications: solar cell electrodes, big electrodes in micro-device, contact pad for device, microfluidics device, lab-on-a-chip
- Image pixels: 1000 x 1000
- sample stage tilt correction

Specification

- Minimum linewidth: ~1 μm
- minimum spot size: 1 μm
- maximum writing speed: 600 $\mu\text{m}/\text{sec}$
- Sample stage resolution: 0.125 μm
- Scannable range: 25 mm x 25 mm
- Focal depth: 1 μm

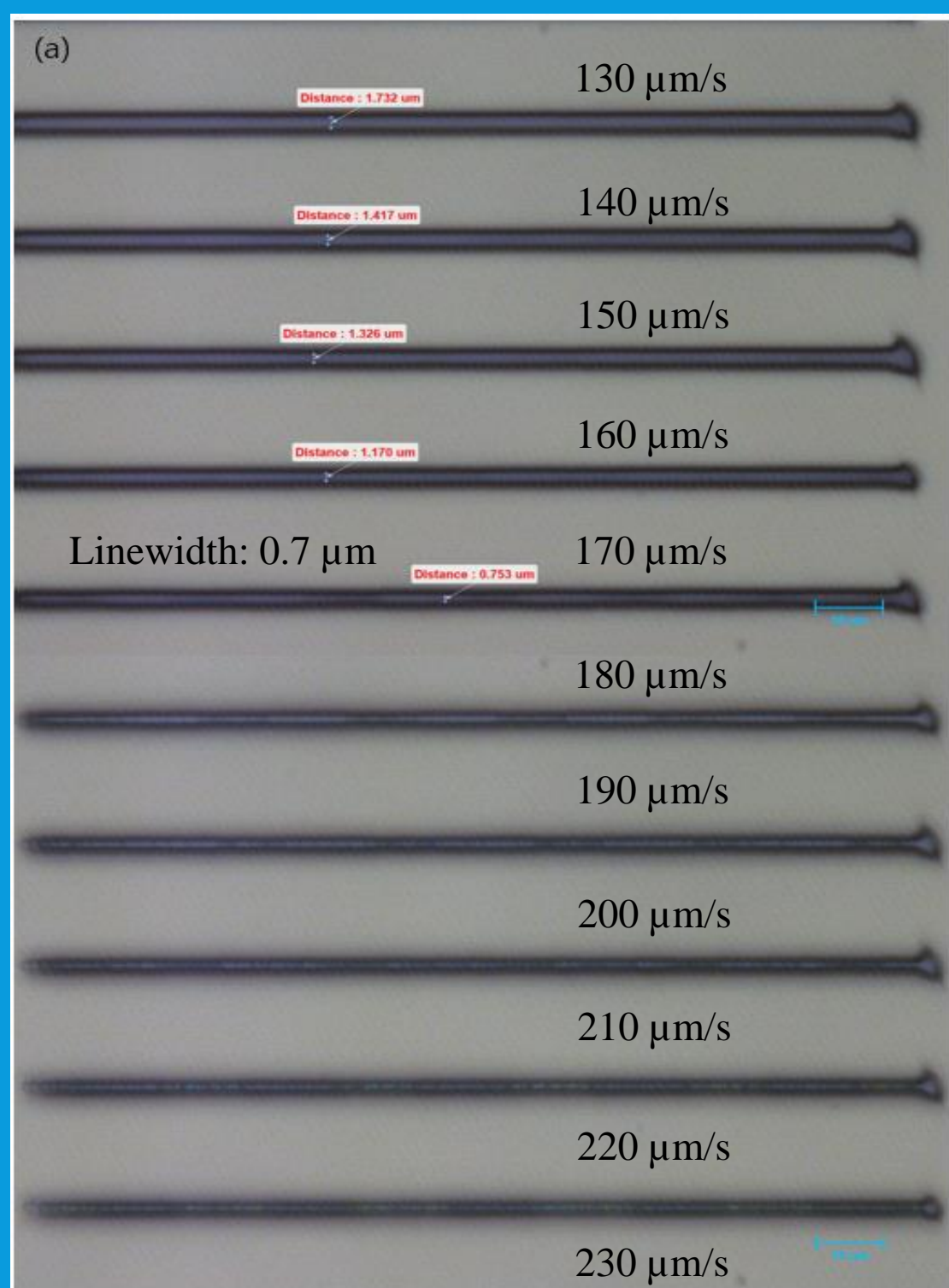
convenience

- ✓ Auto-focusing!
- ✓ Large area scanning stage
- ✓ Magnet holder for electric lead contact
- ✓ Device protection using jumper wire on bread board
- ✓ Keyboard operation → position adjustment
- ✓ Mouse operation → move to a specific location on the sample
- ✓ Software zoom-in and zoom-out for line drawing
- ✓ 2 writing mode: Raster writing and Vector writing
- ✓ Raster writing: filling area after opening external image file
- ✓ Thick (thin) pen writing with high (lower) laser intensity
- ✓ Vector writing: line pattern writing drawn by mouse clicking

EXPERIMENTAL DATA USING UVW₀₂

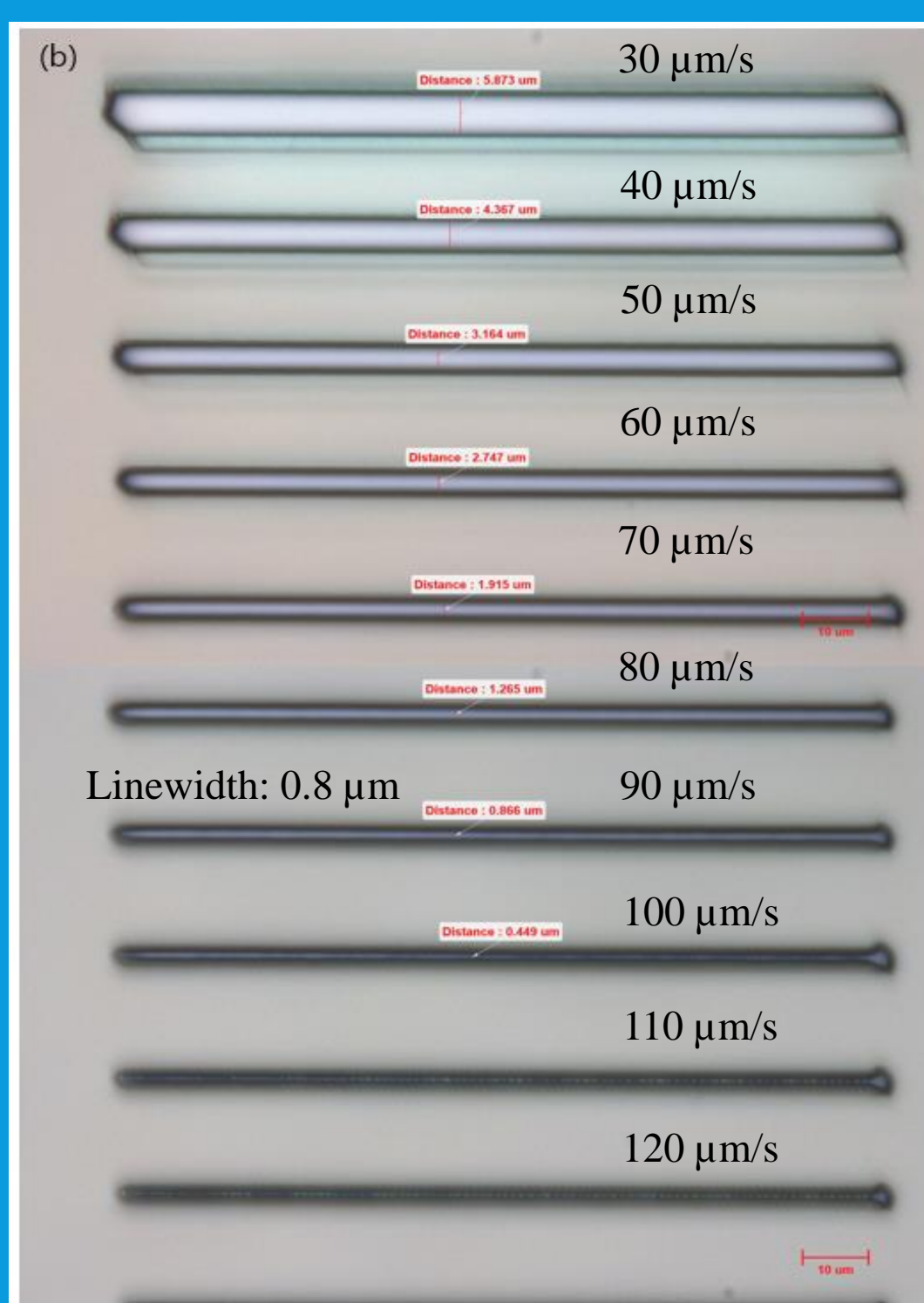
LINEWIDTH VS. WRITING SPEED

Laser power: 760 nW



(a) linewidth with changes in laser velocity, ranging from 130-220 $\mu\text{m/s}$, while maintaining a constant laser power of 760 nW. At a velocity of 170 $\mu\text{m/s}$ and the specified laser power, the line width narrows down to approximately 0.7 μm .

Laser power: 590 nW



(b) The drawing speed from 30- 120 $\mu\text{m/s}$, with the laser power constant at 590 nW. At a speed of 90 $\mu\text{m/s}$ at this laser power, the resulting linewidth measures about 0.8 μm

WRITING SPEED VS. LASER POWER ANALYSIS

- Photoresist used: PR (AZ® GXR-601-46 cps) spin-coating at 4000 rpm → 90 °C soft baking

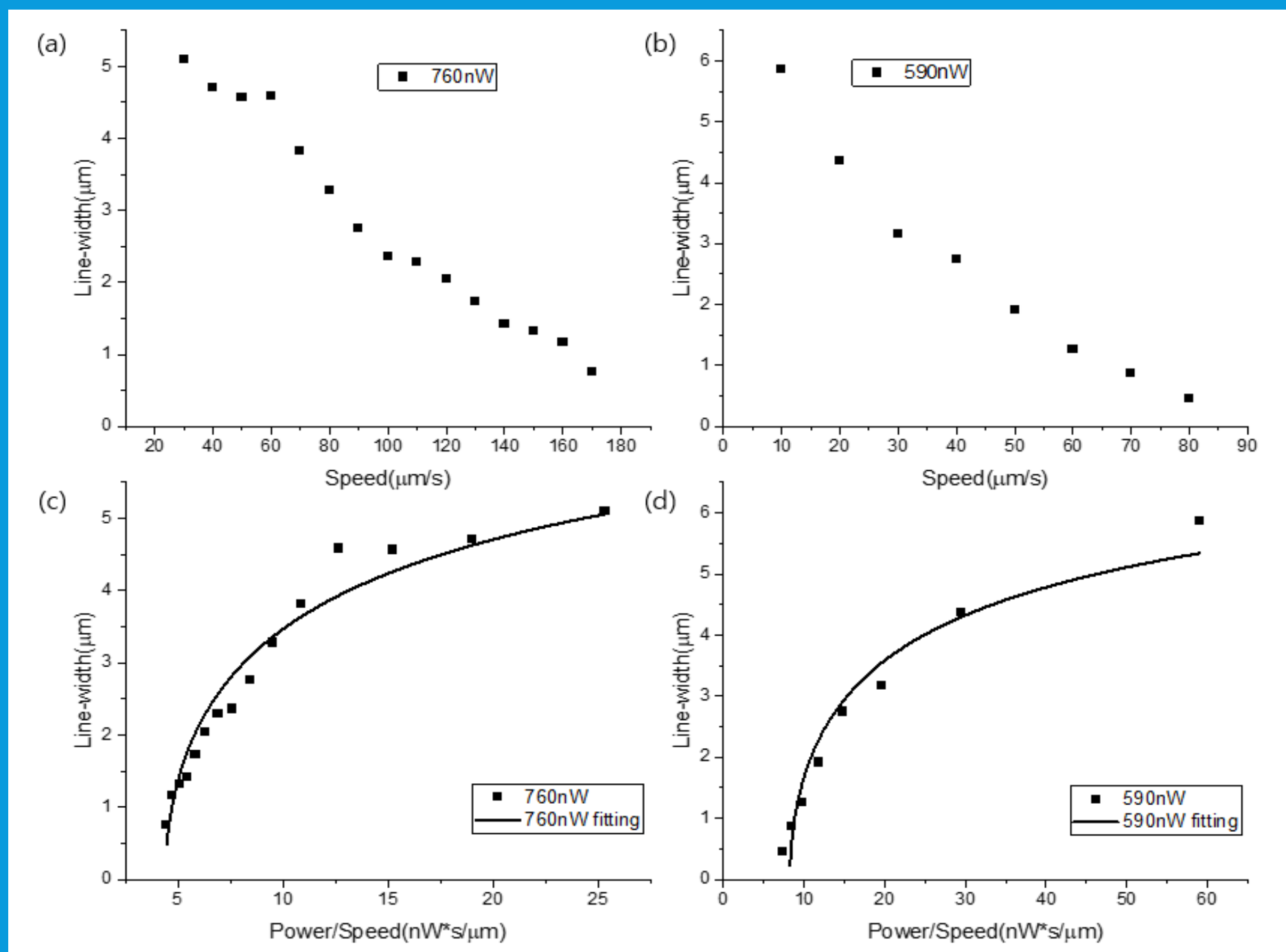


Figure 2 (a-b) The correlation between drawing speed and linewidth at laser power of 590 nW and 760 nW, respectively. (c-d) demonstrate the relationship between linewidth and the power-to-speed ratio for 590 nW and 760 nW laser powers, respectively.

LIFT-OFF PROCESS FOR ELECTRODE PATTERNING ON MoS_2

- bilayer photoresist used: polymethylglutarimide (PMGI, SF9) resist spin-coating at 4000 rpm → soft bake @ 160-210 °C → PR (AZ® GXR-601-46 cps) spin-coating at 4000 rpm → 90 °C soft baking

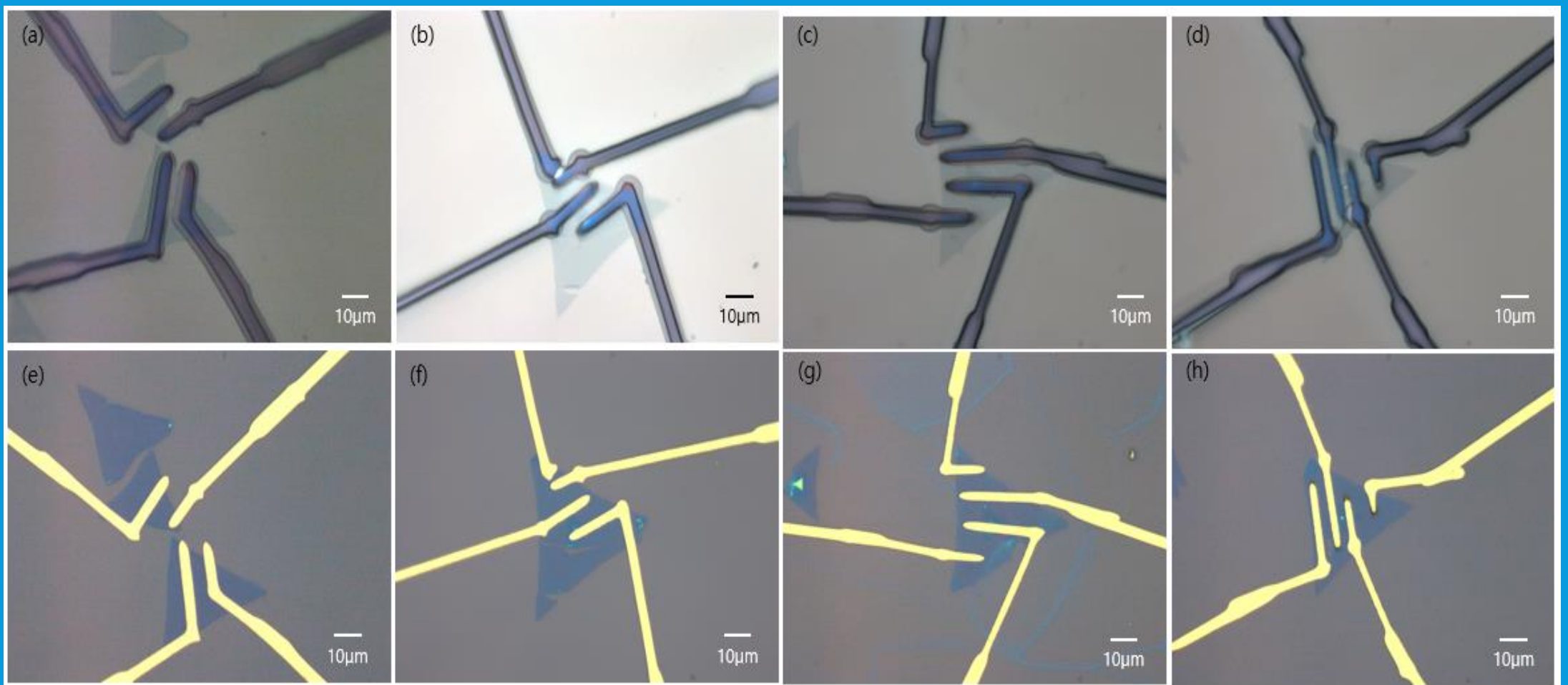


Figure 3. (a-d) Electrode patterning on a MoS_2 sample, $\sim 30 \mu\text{m}$ in size, using maskless lithography. These micrographs were taken after development. (e-h) Micrographs of the final devices are shown after the lift-off process. Deposition of 10 nm of Bi, succeeded by the deposition of 40 nm of Au using an E-beam evaporator.



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